



Solid State Devices, Inc.

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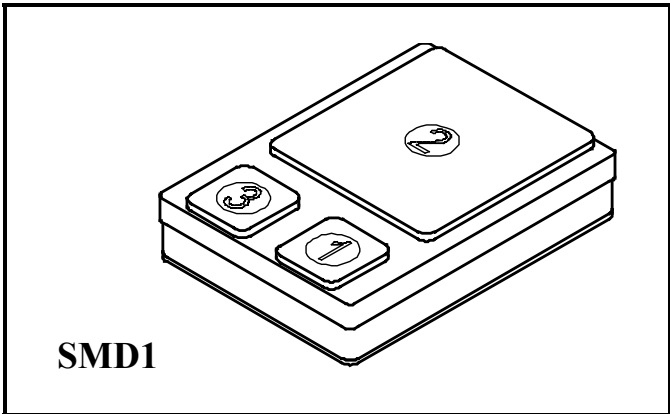
**SSR1008
SSR1009
SSR1010**

**10 AMP
100 VOLTS
SCHOTTKY RECTIFIER**

Designer's Data Sheet

FEATURES:

- Extremely Low Forward Voltage Drop
- Low Reverse Leakage
- Hermetically Sealed Power Surface Mount Package
- Guard Ring for Overvoltage Protection
- Eutectic Die Attach
- 175°C Operating Junction Temperature
- TX, TXV, or Space Level Screening Available



MAXIMUM RATINGS

RATING	SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage and DC Blocking Voltage SSR1008 SSR1009 SSR1010	V_{RRM} V_{RWM} V_R	80 90 100	Volts
Average Rectified Output Current ^{1/} (Resistive Load, 60Hz, Sine Wave, TA=25°C)	I_O	10	Amps
Peak Surge Current ^{1/} (8.3 ms Pulse, Half Sine Wave, superimposed on I_O , allow junction to reach equilibrium between pulses, TA=25°C)	I_{FSM}	200	Amps
Operating and Storage Temperature	T_{OP} & T_{STG}	-65 to +175	°C
Maximum Thermal Resistance ^{1/} Junction to Case	$R_{\theta JC}$	1.6	°C/W

Notes: ^{1/} For optimal performance, leads 1 & 3 should be connected.

NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: RS0197D

DOC



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ELECTRICAL CHARACTERISTICS

CHARACTERISTICS	SYMBOL	MAXIMUM	UNIT
Instantaneous Forward Voltage Drop ($I_F = 1 \text{ Adc}$, $T_A = 25^\circ \text{C}$, Pulse) ($I_F = 5 \text{ Adc}$, $T_A = 25^\circ \text{C}$, Pulse) ($I_F = 10 \text{ Adc}$, $T_A = 25^\circ \text{C}$, Pulse)	V_{F1} V_{F2} V_{F3}	0.55 0.68 0.75	Vdc
Instantaneous Forward Voltage Drop ($I_F = 10 \text{ Adc}$, $T_A = -55^\circ \text{C}$, Pulse)	V_{F4}	0.83	Vdc
Reverse Leakage Current (Rated V_R , $T_A = 25^\circ \text{C}$, Pulse)	I_{R1}	100	μA
Reverse Leakage Current (Rated V_R , $T_A = 100^\circ \text{C}$, Pulse)	I_{R2}	5	mA
Junction Capacitance ($V_R = 10 \text{ Vdc}$, $T_A = 25^\circ \text{C}$, $f = 1 \text{ MHz}$)	C_J	400	pF

